

	Type	L #	Hits	Search Text	DBs	Time Stamp
1	BRS	L2	4	((light adj emitting adj (diode device)) and gan) and (mqw (multiple adj quantum adj well))) and @ay<1994	USPAT; US-PGPU B; EPO; JPO; DERWENT ; IBM TDB	2002/08/11 20:16
2	BRS	L8	0	((light adj emitting adj (diode device)) and ingan) and (mqw (multiple adj quantum adj well))) and @ay<1994	USPAT; US-PGPU B; EPO; JPO; DERWENT ; IBM TDB	2002/08/11 20:18
3	BRS	L9	166	(light adj emitting adj (diode device)) and (mqw (multiple adj quantum adj well))) and @ay<1994	USPAT; US-PGPU B; EPO; JPO; DERWENT ; IBM TDB	2002/08/11 20:20
4	BRS	L10	0	9 and (ingan gainn)	USPAT; US-PGPU B; EPO; JPO; DERWENT ; IBM TDB	2002/08/11 20:19
5	BRS	L11	0	(light adj emitting adj (diode device)) and (ingan gainn) adj (mqw (multiple adj quantum adj well))) and @ay<1994	USPAT; US-PGPU B; EPO; JPO; DERWENT ; IBM TDB	2002/08/11 20:20